

## GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER With Power Detector, 37 - 40 GHz

### Typical Applications

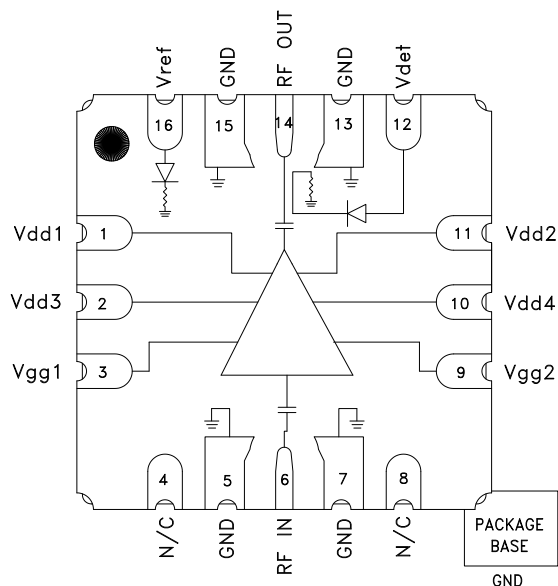
The HMC7229LS6 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- VSAT & SATCOM
- Military & Space

### Features

- P1dB Output Power: 31.5 dBm
- Saturated Output Power: +32 dBm
- High Output IP3: 40 dBm
- High Gain: 24 dB
- DC Power Supply: 6V @ 1200 mA
- 50 Ohm Matched Input/Output
- 16 Lead 6x6 mm SMT Package: 36 mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC7229LS6 is a four-stage GaAs pHEMT MMIC 1 Watt Power Amplifier which operates between 37 and 40 GHz. The HMC7229LS6 provides 24 dB of gain, +32 dBm of saturated output power, and 18% PAE from a +6V supply. With an excellent OIP3 of +40 dBm, the HMC7229LS6 is ideal for high linearity applications in military and space as well as point-to-point and point-to-multi-point radios. The RF I/Os are internally matched and DC blocked for ease of integration into higher level assemblies. The HMC7229LS6 is housed in a ceramic air cavity package which exhibits low thermal resistance and is compatible with surface mount manufacturing techniques.

### Electrical Specifications

$T_A = +25^\circ\text{C}$ ,  $V_{dd} = V_{dd1} = V_{dd2} = V_{dd3} = V_{dd4} = +6\text{V}$ ,  $I_{dd} = 1200\text{ mA}$  [1]

Parameter	Min.	Typ.	Max.	Units
Frequency Range	37 - 40			GHz
Gain	21	24		dB
Gain Variation over Temperature		0.058		dB/°C
Input Return Loss		16		dB
Output Return Loss		14		dB
Output Power for P1dB Compression	28.5	31.5		dBm
Saturated Output Power (Psat)		32		dBm
Output Third Order Intercept (IP3) [2]		40		dBm
Total Supply Current (Idd)		1200		mA

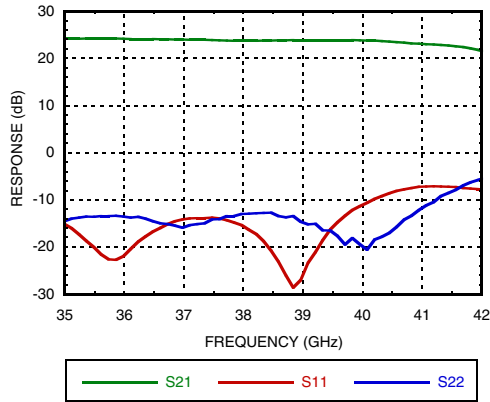
[1] Adjust Vgg between -2 to 0V to achieve Idd = 1200mA typical

[2] Measurement taken at Pout / tone = +20dBm.

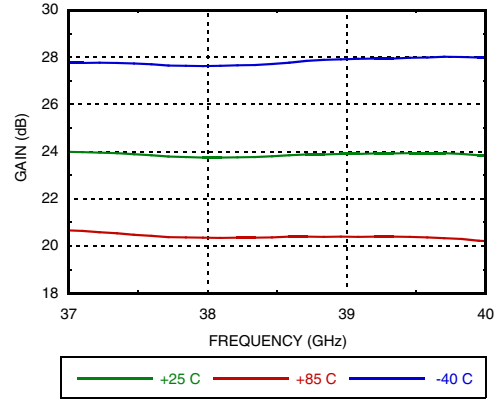


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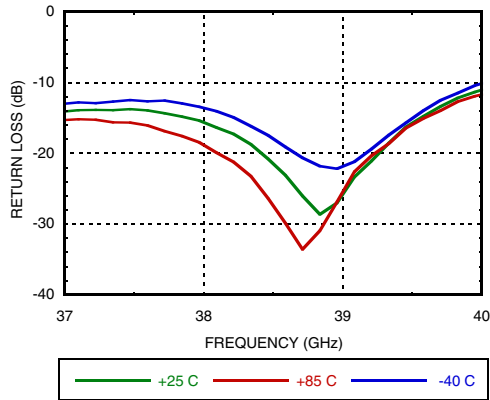
**Gain & Return Loss**



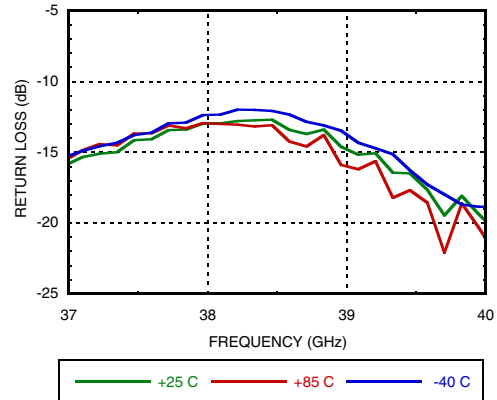
**Gain vs. Temperature**



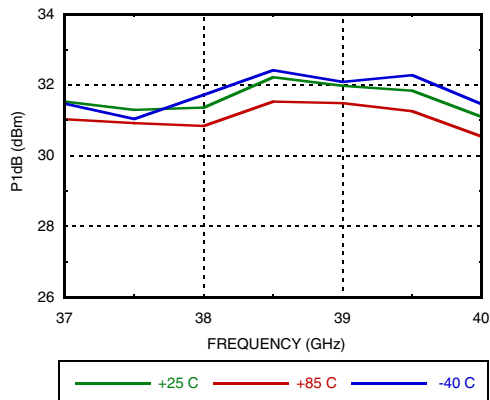
**Input Return Loss vs. Temperature**



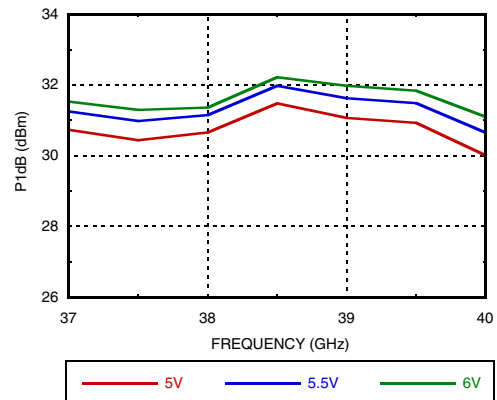
**Output Return Loss vs. Temperature**



**P1dB vs. Temperature**



**P1dB vs. Supply Voltage**

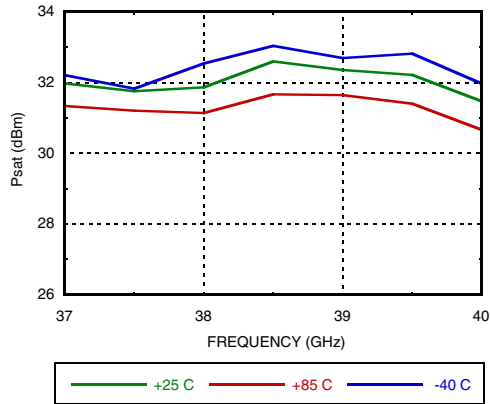




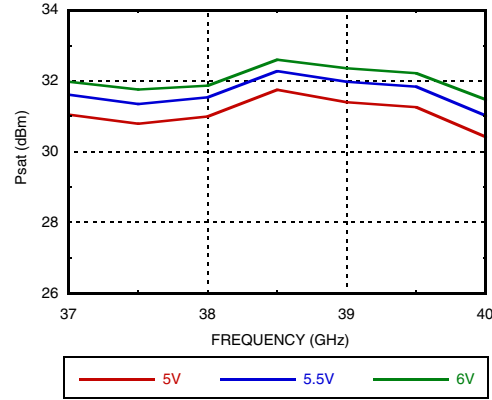
## GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER With Power Detector, 37 - 40 GHz

AMPLIFIERS - LINEAR & POWER - SMT

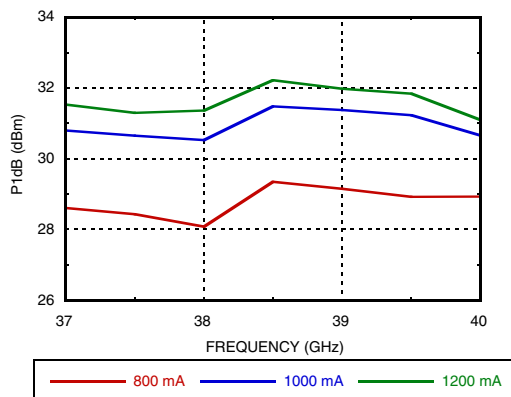
**Psat vs. Temperature**



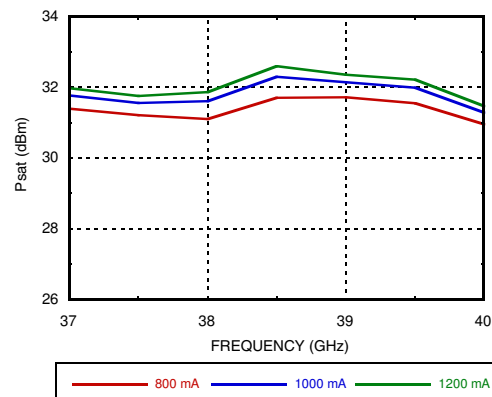
**Psat vs. Supply Voltage**



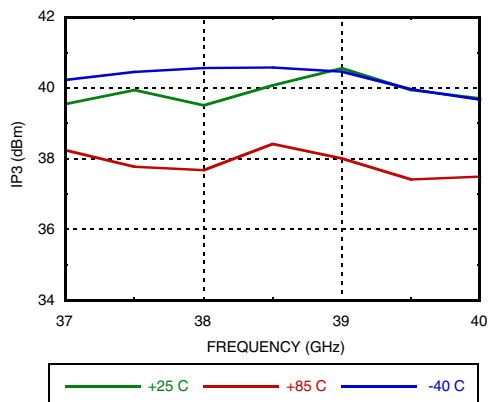
**P1dB vs. Supply Current**



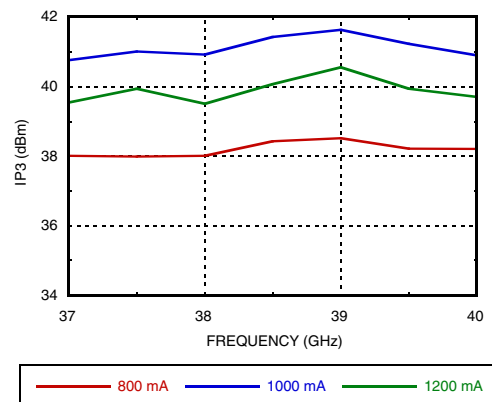
**Psat vs. Supply Current**



**Output IP3 vs. Temperature, Pout/tone = +20 dBm**



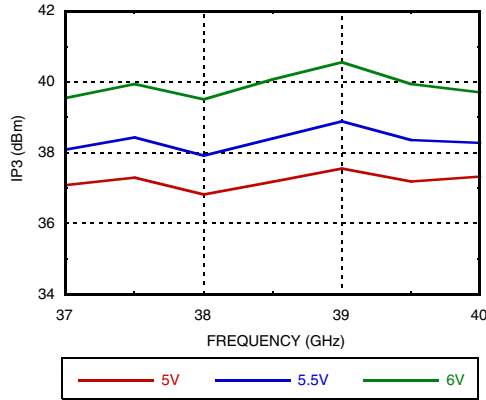
**Output IP3 vs. Supply Current, Pout/tone = +20 dBm**



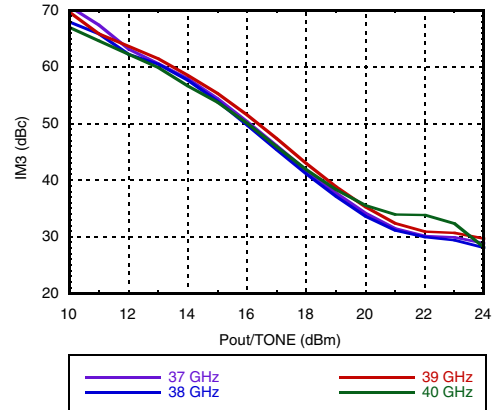


## GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER With Power Detector, 37 - 40 GHz

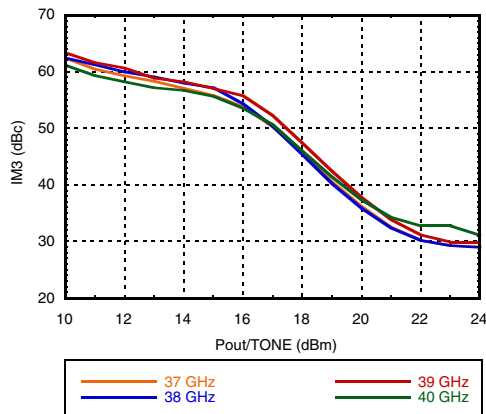
**Output IP3 vs. Supply Voltage,  
Pout/tone = +20 dBm**



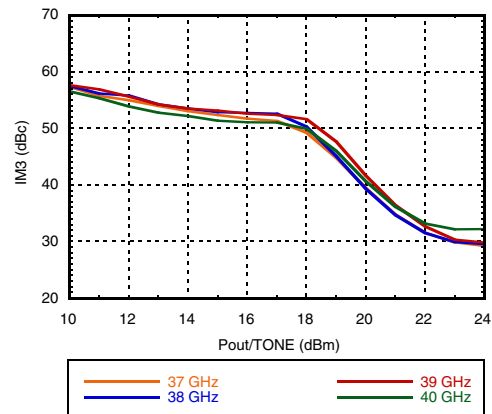
**Output IM3 @ Vdd = +5V**



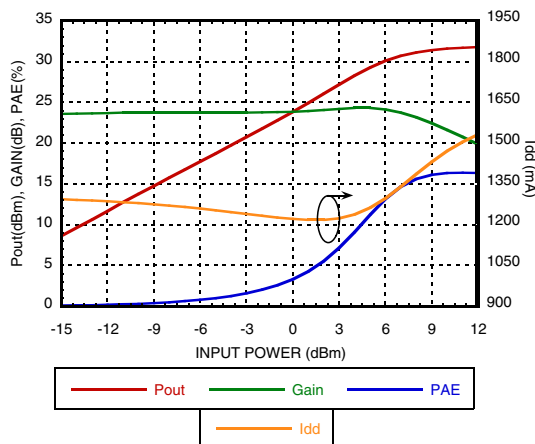
**Output IM3 @ Vdd = +5.5V**



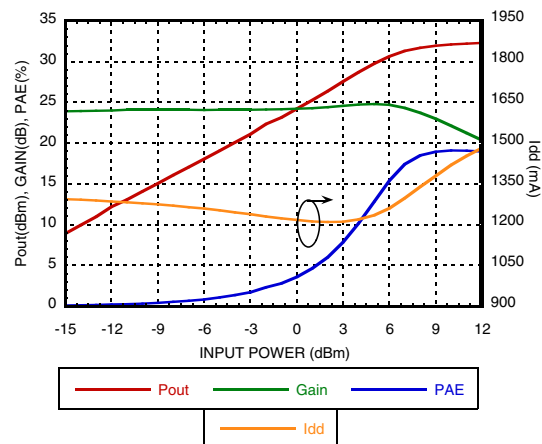
**Output IM3 @ Vdd = +6V**



**Power Compression @ 38 GHz**



**Power Compression @ 39 GHz**

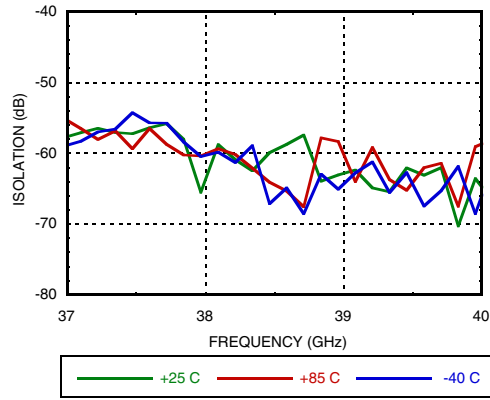




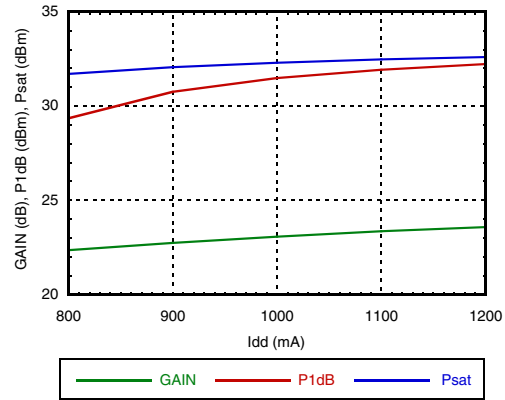
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AMPLIFIERS - LINEAR & POWER - SMT

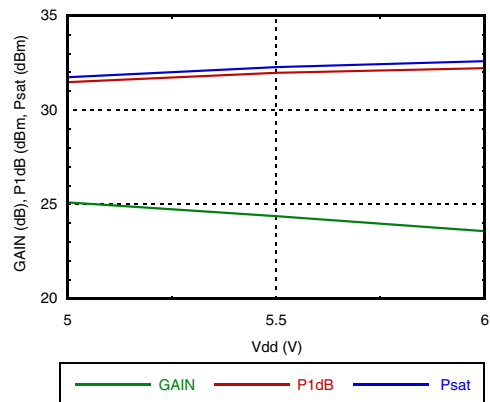
**Reverse Isolation vs. Temperature**



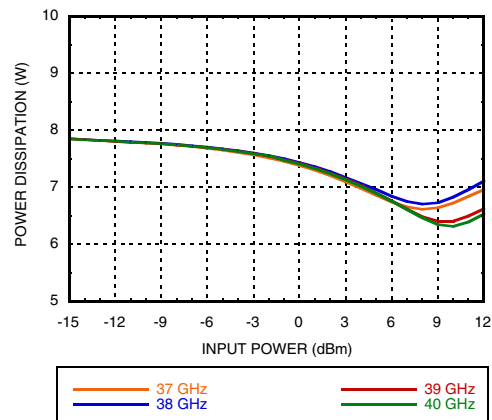
**Gain & Power vs. Supply Current @ 38.5 GHz**



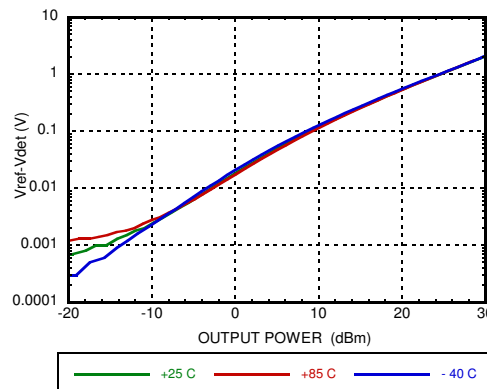
**Gain & Power vs. Supply Voltage @ 38.5 GHz**



**Power Dissipation**



**Detector Voltage vs. Temperature @ 38.5 GHz**





## GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER With Power Detector, 37 - 40 GHz

### Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+7V
RF Input Power (RFIN)	+21 dBm
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 95 mW/°C above 85 °C)	9.0 W
Thermal Resistance (channel to ground paddle)	10 °C/W
Operating Temperature	-65°C to +150°C
Storage Temperature	-40°C to 85°C
ESD Sensitivity (HBM)	Class 0, Passed 150V

### Typical Supply Current vs. Vdd

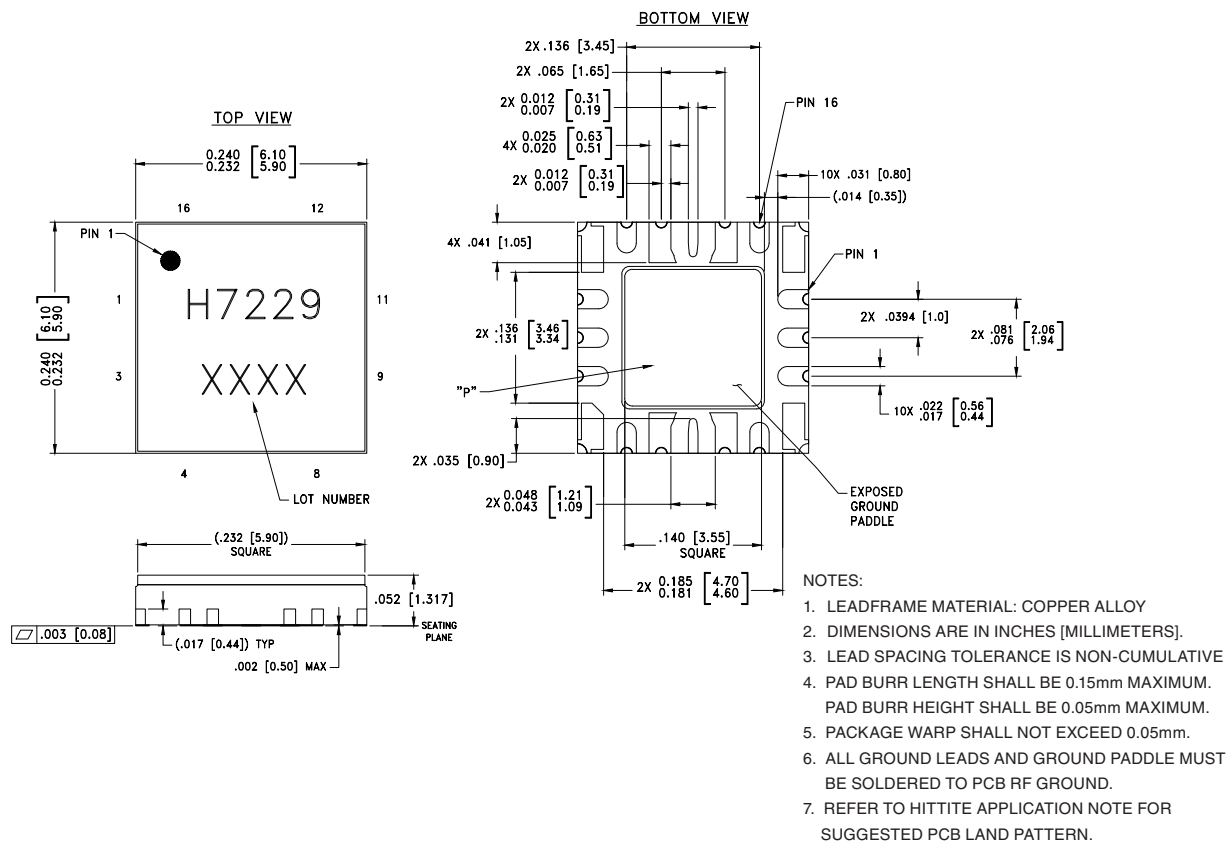
Vdd (V)	Idd (mA)
+5	1200
+5.5	1200
+6	1200

Adjust Vgg1 to achieve Idd = 1200 mA



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



### Package Information

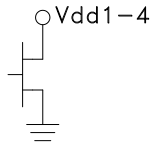
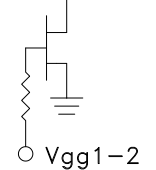

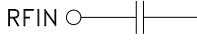
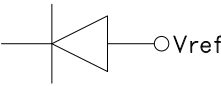
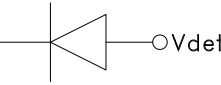
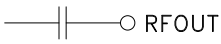
Part Number	Package Body Material	Lead Finish	MSL Rating <sup>[2]</sup>	Package Marking <sup>[1]</sup>
HMC7229LS6	ALUMINA WHITE	Gold over Nickel	N/A <sup>[3]</sup>	H7229 XXXX

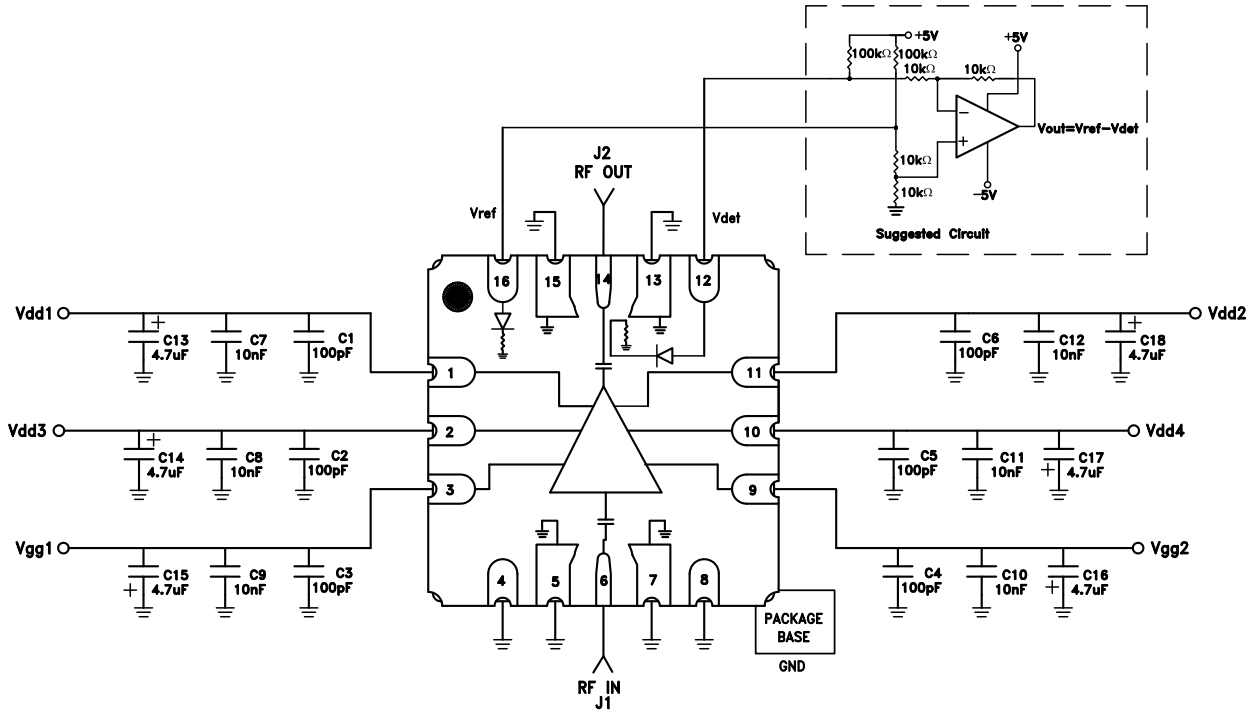
[1] 4-Digit lot number XXXX.

[2] Max peak reflow temperature of 260 °C.

[3] Not Applicable to air cavity packages.

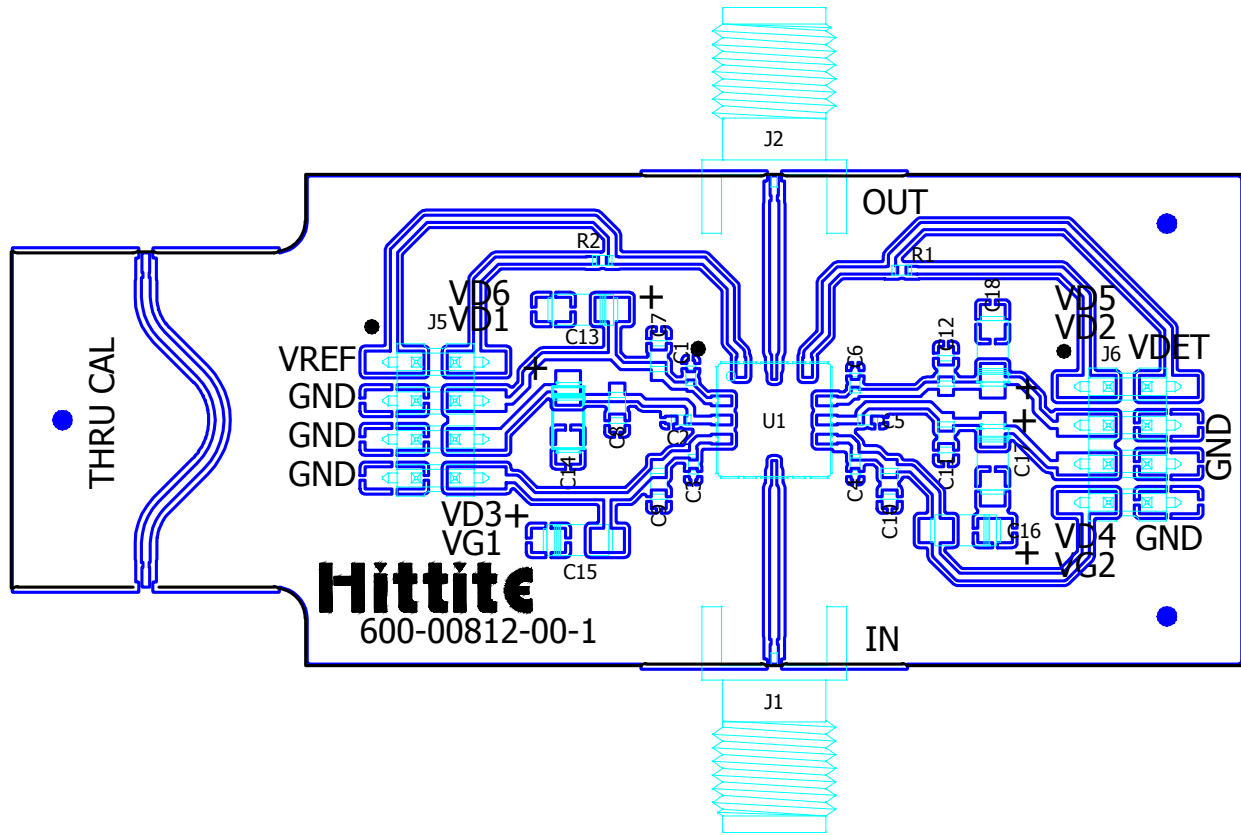
**Pin Descriptions**

Pin Number	Function	Description	Pin Schematic
1, 2, 10, 11	Vdd1, Vdd3, Vdd4, Vdd2	Drain bias voltage. External bypass capacitors of 100 pF, 10 nF and 4.7 $\mu$ F are required for each pin.	
3, 9	Vgg1, Vgg2	Gate control for PA. Adjust Vgg to achieve recommended bias current. External bypass caps 100 pF, 10 nF and 4.7 $\mu$ F are required. Apply Vgg bias to either pin 3 or pin 9.	
4, 8	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
5, 7, 13, 15	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	
6	RF IN	This pin is AC coupled and matched to 50 Ohms.	
16	Vref	DC voltage of diode biased through external resistor used for temperature compensation of Vdet. See application circuit.	
12	Vdet	DC voltage representing RF output power rectified by diode which is biased through an external resistor. See application circuit.	
14	RF OUT	This pin is AC coupled and matched to 50 Ohms.	

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**Application Circuit**




### Evaluation PCB



### List of Materials for Evaluation PCB EV1HMC7229LS6 [1]

Item	Description
J1 - J2	"K" Connector, SRI
J5 - J6	DC Pin
C1 - C6	100 pF Capacitor, 0402 Pkg.
C7 - C12	10000 pF Capacitor, 0603 Pkg..
C13 - C18	4.7 uF Capacitor, Case A Pkg.
R1 - R2	40.2K Ohm Resistor, 0402 Pkg.
U1	HMC7229LS6 Amplifier
PCB [2]	600-00812-00 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



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**Notes**

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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